NSN 5961-01-422-6529

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View Online at https://aerobasegroup.com/nsn/5961-01-422-6529

Inclosure Material:

Plastic

Overall Length:

0.119 inches

Overall Height:

0.061 inches

Overall Width:

0.103 inches

Internal Configuration:

Field effect-dual gate

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

20.0 drain to source voltage

Current Rating Per Characteristic:

30.00 milliamperes source cutoff current of standard range

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Test Data Document:

37695-647468 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

4 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0